Effect of cool down rate in cryomodules on cavities Q

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Introduction

- For CW operation cryogenics is a cost driver
- Minimize cryogenic load $P_{diss} \sim R_s \sim 1/Q$
- $R_s = R_{BCS}(f,T) + R_0$
- One of the R₀ contributions is 'trapped magnetic flux', which can be substantial if there are thermocurrents generating a magnetic field, which gets trapped during cooldown through T_c

Q₀ measurements

- HoBiCaT test facility
- Temperatures down to 1.5 K
- Horizontal, fully equipped cavity weld into Helium tank
- **Near** b=1



Cavity cool down procedure

Temperatures of cool down



R_{surf} after initial cooldown



Thermal cycling procedure

- Start with superconducting cavity
- Turn off Helium supply (JT valve)
- Evaporate Helium in tank
- Wait. Make sure cavity is just above T_c and normal conducting.
- Restart cryo plant





Influence of thermal cycling on R_{surf}



Thermocurrents

Thermoelectric effect: Voltage due to material and temperature dependent charge carrier velocity

$$U_{thermo} = (S_{Niobium} - S_{Titanium}) \times DT$$

S are Seebeck coefficients

Set up model experiment

Master thesis Julia Vogt, see poster WEPWO004 for further details





Cavity-tank system as "thermoelement" Close circuit to obtain thermocurrent.







Initial Cooldown at 16.2 MV/m

Q(2.0 K) = 2.5×10^{10} Q(1.8 K) = 3.5×10^{10} Q(1.6 K) = 5.0×10^{10} 10 K thermal cycle at 16.2 MV/m

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N. Valles – High Q Cavity Operation in the

Cornell HTC – TTC Topical Meeting on CW-

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HTC-3: Nb properties

- SRIMP used to fit SRF properties of cavity before and after thermal cycle
- Assumption: Material properties remain constant during cycle.
 Only residual resistance changes.





High O Cryomodules



He gas input

- Magnetic shielding is essential
- Thermal gradients across cavity should be minimized to get high Qs
- Cavity temperature gradient ~0.2 K
- Cool down rate through T_c : ~ 0.4 K/hr

6 Cernox temperature sensors mounted on top and bottom of end cells and center cell

